# 1. General description

PNP high power bipolar transistor in a power DPAK, TO-252 (SOT428C) Surface-Mounted Device (SMD) plastic package.

NPN complement: MJD44H11

### 2. Features and benefits

- · High thermal power dissipation capability
- · High energy efficiency due to less heat generation
- Electrically similar to popular MJD45H series
- Low collector emitter saturation voltage
- Fast switching speeds

# 3. Applications

- · Power management
- Load switch
- Linear mode voltage regulator
- · Constant current drive backlighting application
- Motor drive
- · Relay replacement

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-80	V
I <sub>C</sub>	collector current		-	-	-8	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-16	Α
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -1 V; I <sub>C</sub> = -2 A; T <sub>amb</sub> = 25 °C	60	-	-	



### 80 V, 8 A PNP high power bipolar transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	mb	E
2	С	collector		в -{м
3	Е	emitter		C; mb
mb	С	mounting base; connected to collector	DPAK (SOT428C)	aaa-029523

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
MJD45H11	DPAK	Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428C			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
MJD45H11	MJD45H11

# 8. Limiting values

#### Table 5. Limiting values

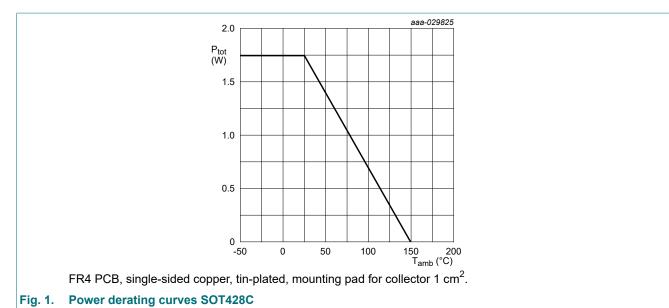
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-80	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-6	V
Ic	collector current			-	-8	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-16	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> ≤ 25 °C	[1]	-	20	W
		T <sub>amb</sub> ≤ 25 °C	[2]	-	1.75	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Total power dissipation junction to mounting base.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.

### 80 V, 8 A PNP high power bipolar transistor

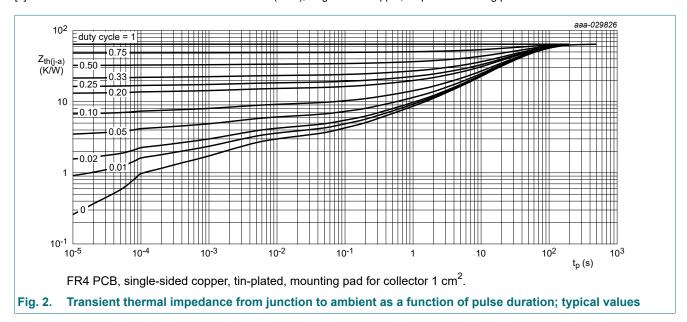


# 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	in free air		-	-	6.25	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient		[1]	-	-	72	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.



### 80 V, 8 A PNP high power bipolar transistor

## 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CES</sub>	collector-emitter cut-off	V <sub>CE</sub> = -64 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-1	μA
	current	V <sub>CE</sub> = -64 V; V <sub>BE</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-1	μΑ
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -1 V; I <sub>C</sub> = -2 A; T <sub>amb</sub> = 25 °C	60	-	-	
		V <sub>CE</sub> = -1 V; I <sub>C</sub> = -4 A; T <sub>amb</sub> = 25 °C	40	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -8 A; $I_B$ = -400 mA; $T_{amb}$ = 25 °C	-	-	-1	V
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -8 A; $I_B$ = -800 mA; $T_{amb}$ = 25 °C	-	-	-1.5	V
t <sub>on</sub>	turn-on time	I <sub>C</sub> = -5 A; I <sub>Bon</sub> = -0.5 A; I <sub>Boff</sub> = 0.5 A;	-	225	-	ns
ts	storage time	V <sub>CC</sub> = -12.5 V; T <sub>amb</sub> = 25 °C	-	280	-	ns
t <sub>f</sub>	fall time		-	100	-	ns
t <sub>off</sub>	turn-off time		-	380	-	ns
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	80	-	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; $I_{C}$ = -500 mA; f = 100 MHz; $T_{amb}$ = 25 °C	-	80	-	MHz

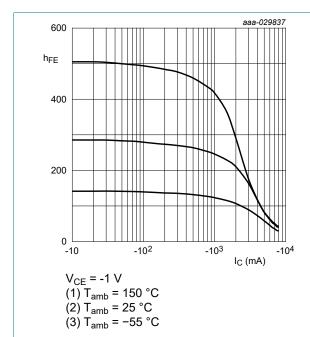


Fig. 3. DC current gain as a function of collector current; typical values

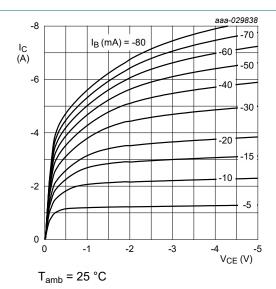
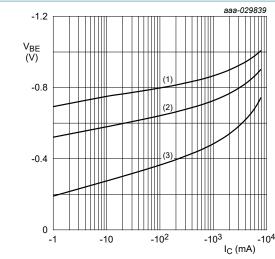


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

### 80 V, 8 A PNP high power bipolar transistor

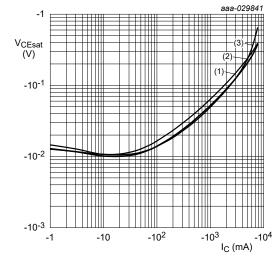


$$V_{CF} = -5 V$$

$$(1) T_{amb} = -55 ° ($$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



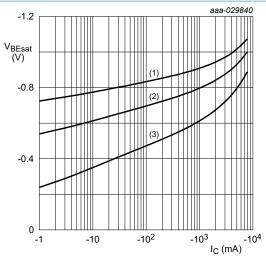
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

$$(2) T_{amb} = 25 °C$$

$$(3) T_{amb} = -55 °C$$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



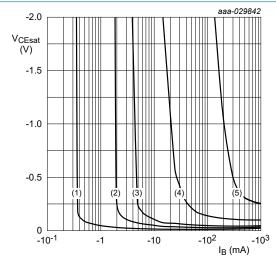
$$I_{\rm C}/I_{\rm B} = 20$$

$$I_{C}/I_{B} = 20$$
  
(1)  $T_{amb} = -55 \,^{\circ}C$   
(2)  $T_{amb} = 25 \,^{\circ}C$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



(1)  $I_C = -100 \text{ mA}$ 

(2)  $I_C = -500 \text{ mA}$ 

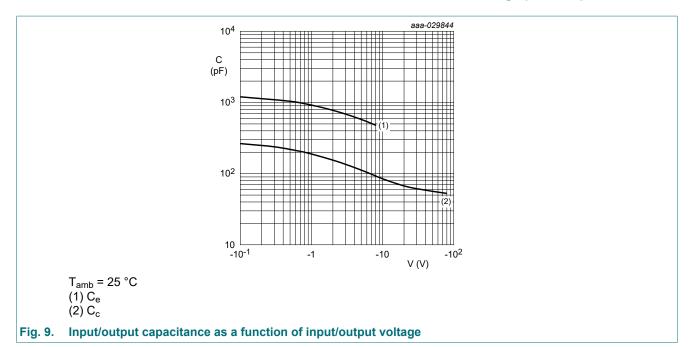
(3)  $I_C = -1000 \text{ mA}$ 

 $(4) I_C = -3000 \text{ mA}$ 

 $(5) I_C = -8000 \text{ mA}$ 

Fig. 8. Collector-emitter saturation region as a function of base current; typical values

### 80 V, 8 A PNP high power bipolar transistor



### 80 V, 8 A PNP high power bipolar transistor

## 11. Test information

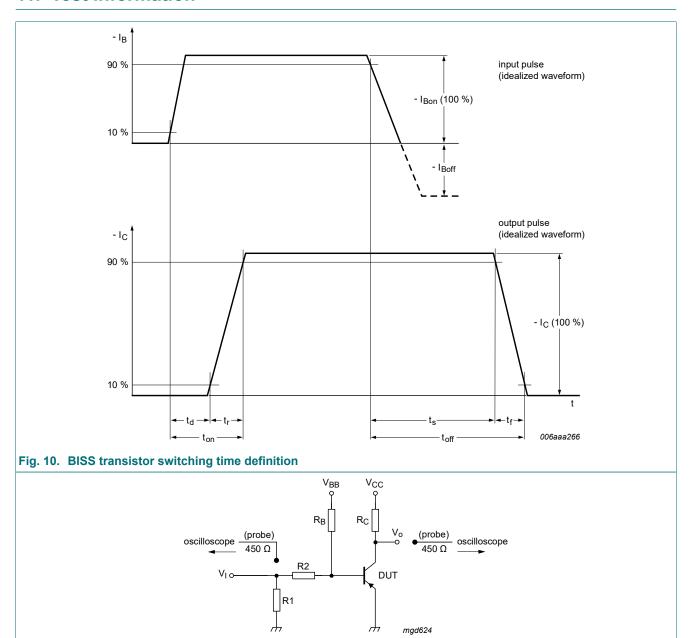
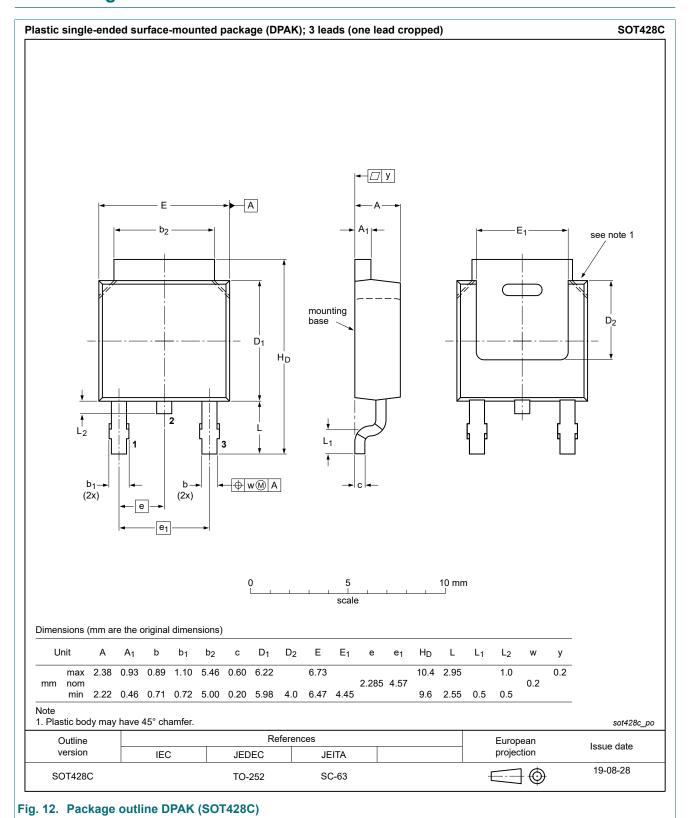


Fig. 11. Test circuit for switching times

### 80 V, 8 A PNP high power bipolar transistor

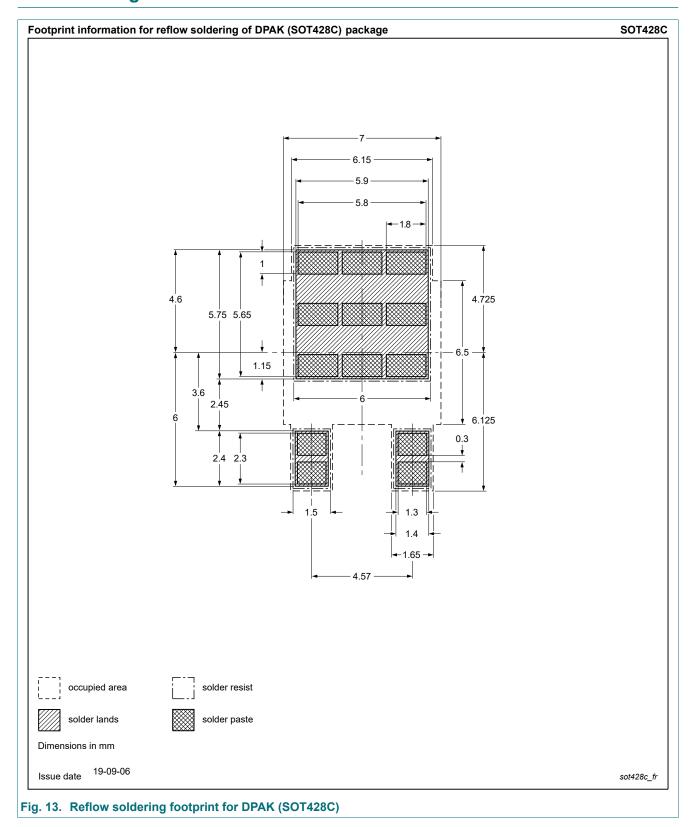
# 12. Package outline



**Product data sheet** 

80 V, 8 A PNP high power bipolar transistor

# 13. Soldering



### 80 V, 8 A PNP high power bipolar transistor

# 14. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
MJD45H11 v.3	20190912	Product data sheet	-	MJD45H11 v.2			
Modifications:	Package outline ada	Package outline adapted to SOT428C					
MJD45H11 v.2	20190729	Product data sheet	-	MJD45H11 v.1			
MJD45H11 v.1	20190528	Preliminary data sheet	-	-			

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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### 80 V, 8 A PNP high power bipolar transistor

## **Contents**

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	2
	Thermal characteristics	
10	. Characteristics	4
11.	. Test information	7
12	. Package outline	8
	. Soldering	
	. Revision history	
	. Legal information	

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